



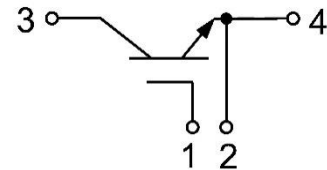
GT150SG120B5H

IGBT Module

Features:

- Field Stop Trench Gate IGBT
- Short Circuit Rated $>10\mu\text{s}$
- Low Switching Loss
- 100% RBSOA Tested($2\times I_c$)
- Low Stray Inductance
- Lead Free, Compliant with RoHS Requirement

Circuit Diagram



Applications:

- Industrial Inverters
- Motor Drives
- UPS Systems

IGBT

Maximum Rated Values of IGBT ($T_c=25^\circ\text{C}$ unless otherwise specified)

V_{CES}	Collector-Emitter Blocking Voltage		1200	V
V_{GES}	Gate-Emitter Voltage		± 20	V
I_c	Continuous Collector Current	$T_c=100^\circ\text{C}$	150	A
		$T_c=25^\circ\text{C}$	300	A
I_{CM}	Repetitive Peak Collector Current	$t_p=1\text{ms}$	300	A
P_D	Maximum Power Dissipation (per IGBT)	$T_c=25^\circ\text{C}$ $T_{Jmax}=175^\circ\text{C}$	938	W



Electrical Characteristics of IGBT ($T_C=25^{\circ}\text{C}$ unless otherwise specified)

Static Characteristics

Symbol	Description	Conditions		Min.	Typ.	Max.	Units
$V_{GE(th)}$	Gate-Emitter Threshold Voltage	$I_C=5.3\text{mA}$, $V_{CE}=V_{GE}$		5.0	5.8	6.5	V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=150\text{A}$, $V_{GE}=15\text{V}$	$T_J=25^{\circ}\text{C}$		1.65	2.00	V
			$T_J=125^{\circ}\text{C}$		1.90		V
			$T_J=150^{\circ}\text{C}$		1.95		V
I_{CES}	Collector-Emitter Leakage Current	$V_{GE}=0\text{V}$, $V_{CE}=V_{CES}$, $T_J=25^{\circ}\text{C}$				1	mA
I_{GES}	Gate-Emitter Leakage Current	$V_{GE}=\pm 20\text{V}$, $V_{CE}=0\text{V}$, $T_J=25^{\circ}\text{C}$				± 200	nA
C_{ies}	Input Capacitance	$V_{CE}=25\text{V}$, $V_{GE}=0\text{V}$, $f=100\text{kHz}$			16.5		nF
C_{oes}	Output Capacitance				2.5		nF
C_{res}	Reverse Transfer Capacitance				0.5		nF

Switching Characteristics

Symbol	Description	Conditions		Min.	Typ.	Max.	Units
t _{d(on)}	Turn-on Delay Time	V _{CC} =600V, I _C =150A, R _{Gon} =6.8Ω, V _{GE} =±15V, Inductive Load	T _J =25°C		437		ns
			T _J =125°C		449		
			T _J =150°C		454		
t _r	Rise Time		T _J =25°C		111		ns
			T _J =125°C		130		
			T _J =150°C		133		
t _{d(off)}	Turn-off Delay Time		T _J =25°C		389		ns
			T _J =125°C		409		
			T _J =150°C		414		
t _f	Fall Time	T _J =25°C		262		ns	
		T _J =125°C		454			
		T _J =150°C		454			
E _{on}	Turn-on Switching Loss	V _{CC} =600V, I _C =150A, R _{Gon} =6.8Ω, V _{GE} =±15V, di/dt=964A/μs(T _J =150°C), Inductive Load	T _J =25°C		15.6		mJ
		T _J =125°C		21.2			
		T _J =150°C		22.6			



E _{off}	Turn-off Switching Loss	V _{CC} =600V, I _C =150A, R _{Goff} =6.8Ω, V _{GE} =±15V, du/dt=3545V/μs(T _J =150°C), Inductive Load	T _J =25°C		10.4		mJ
			T _J =125°C		15.4		
			T _J =150°C		16.0		
Q _g	Total Gate Charge	V _{GE} =+15V...-15V	T _J =25°C		1164		nC
R _{g internal}	Internal Gate Resistor		T _J =25°C		4.5		Ω
SCSOA	V _{CC} =600V, t _p =10μs, V _{GE} =+/-15V, R _{Gon} =6.8Ω, R _{Goff} =6.8Ω, T _J =150°C				630		A
R _{θJC}	IGBT Thermal Resistance: Junction-to-Case					0.16	°C/W

Module

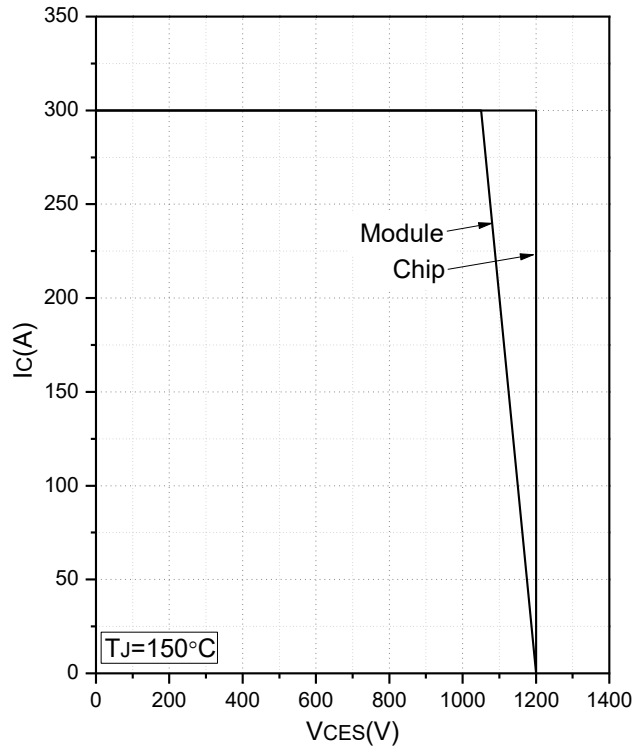
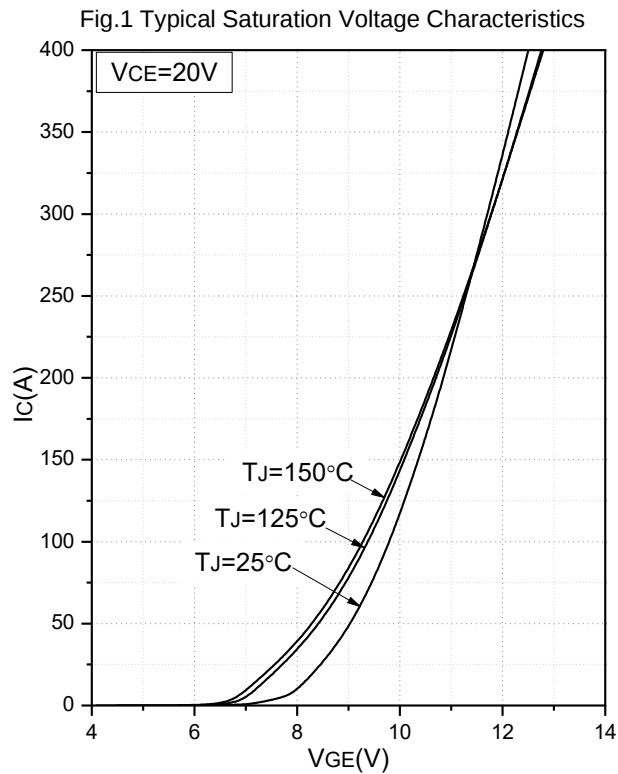
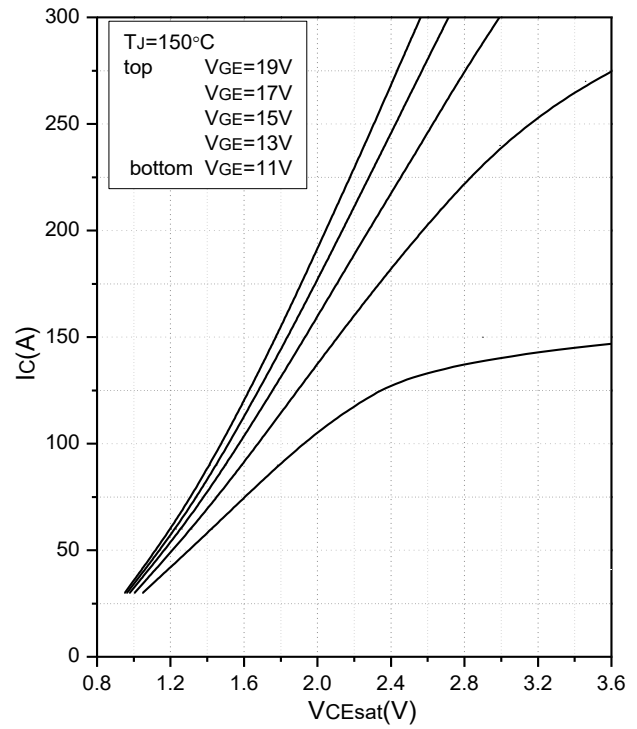
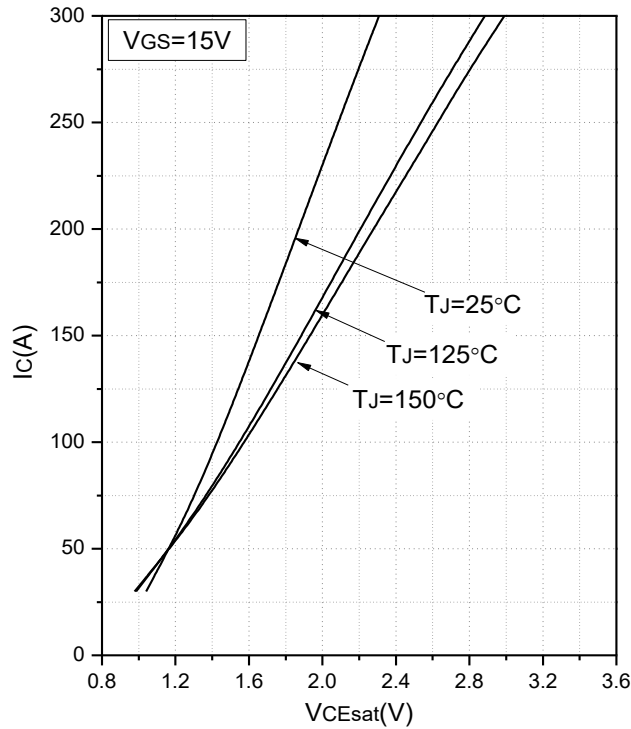
Symbol	Description		Min.	Typ.	Max.	Units
V _{ISO}	Isolation Voltage (All Terminals Shorted)	f=50Hz, 30s	4500			V
Internal Isolation			Al ₂ O ₃			
T _J	Maximum Junction Temperature				175	°C
T _{JOP}	Maximum Operating Junction Temperature Range		-40		+150	°C
T _{stg}	Storage Temperature		-40		+150	°C
R _{θCS}	Case-to-Sink Thermally (Conductive Grease Applied)				0.06	°C/W
CTI	Comparative Tracking Index		200			
T	Power Terminals Screw:M4		1.1		1.5	N·m
T	Mounting Screw:M4		1.1		1.5	N·m
G	Weight			30		g

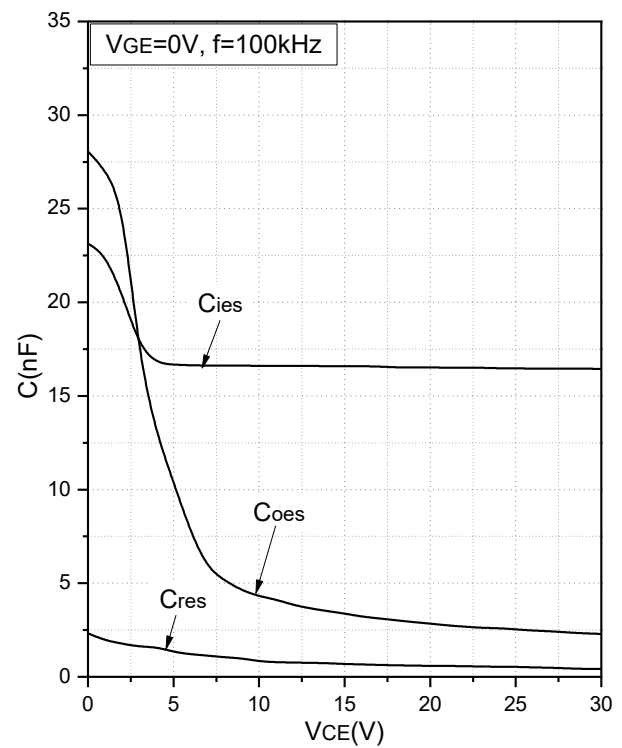
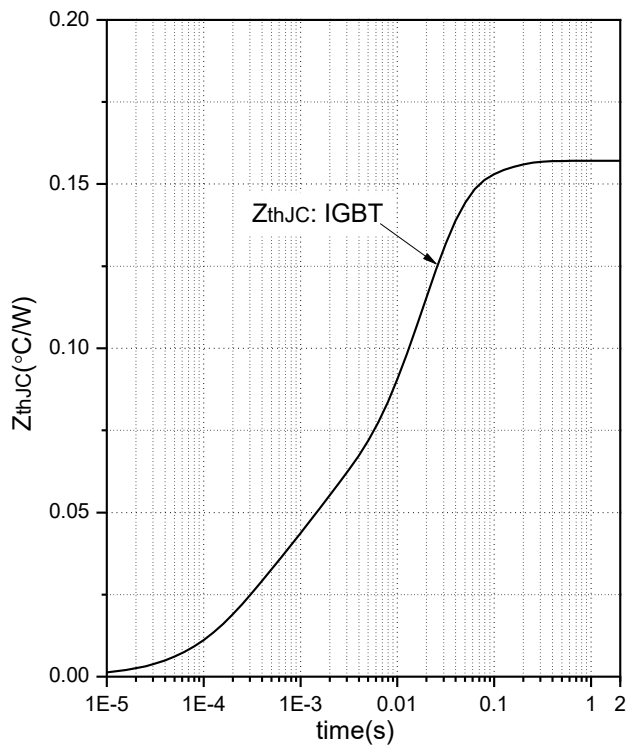
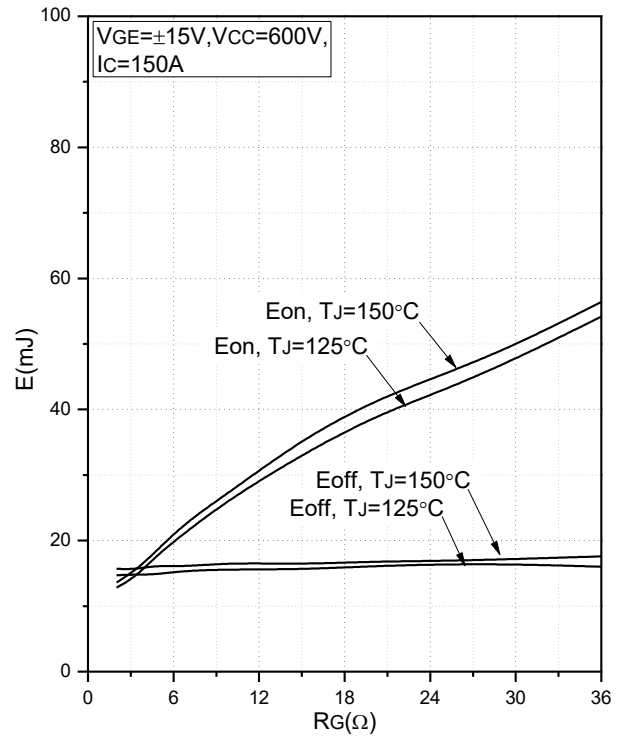
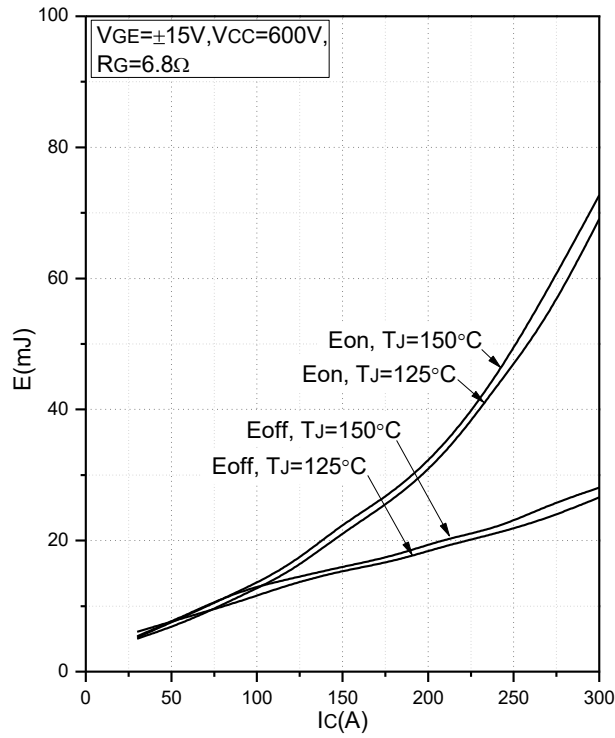


Ordering Information Table

Device code	G	T	150	SG	120	B5	H
	①	②	③	④	⑤	⑥	⑦

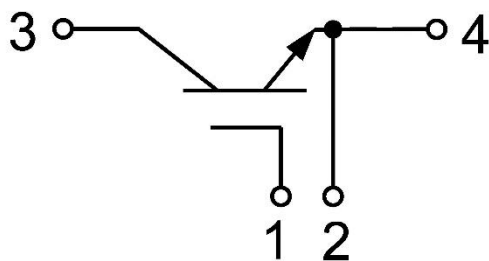
- ① - IGBT Module
- ② - Trench, Low Switching Losses IGBT
- ③ - Rated Current (150=150A)
- ④ - Circuit Configuration: (Single)
- ⑤ - Rated Voltage (120=1200V)
- ⑥ - Package Type
- ⑦ - Test Level (Pass the Important Reliability Test-Industrial Grade)



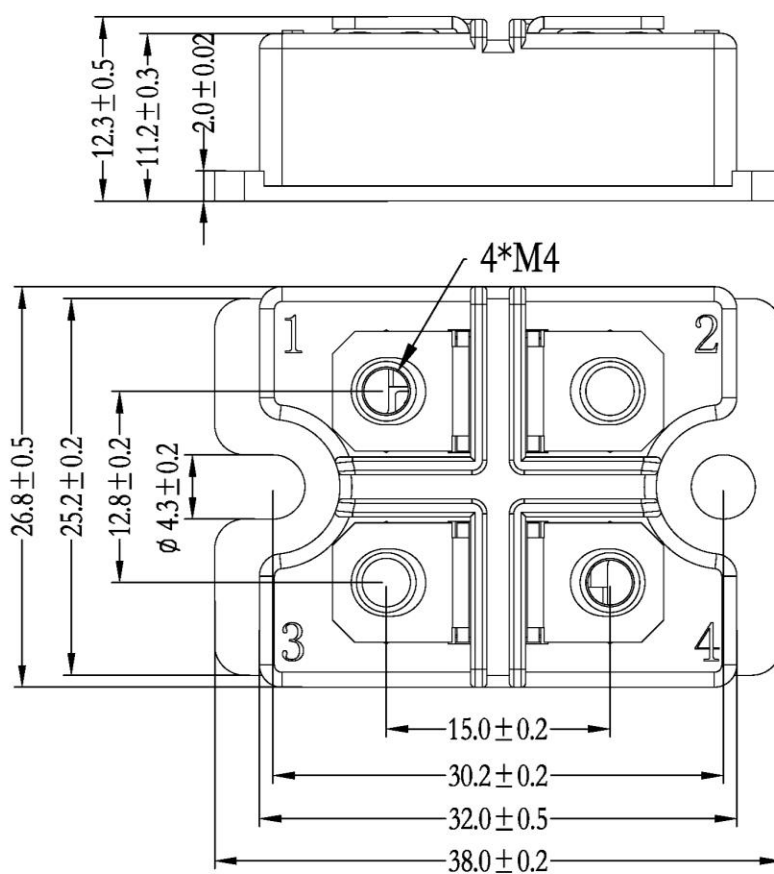




Internal Circuit



Package Outline (Unit: mm):





Revision	Notes
A	Final Version

Announcement

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The released datasheet would be issued with “REV.” + “alphabet characters”.